

# 2.3 — 2.5GHz Power Amplifier & Low Noise Amplifier

Preliminary

### **■** General Description

The GW5540 is an InGaP/GaAs Heterojunction Bipolar Transistor (HBT) IC in a QFN  $2.0 \times 2.0 - 12$  leads plastic package. The power amplifier is implemented as a two-stage monolithic microwave integrated circuit (MMIC), with active bias and output pre-matching. The low noise amplifier is implemented as a one-stage monolithic microwave integrated circuit (MMIC), but external matching circuit is required.

The GW5540 is designed to operate in 2.3 – 2.5GHz frequency range, compatible with 802.11b/g wireless LAN system with high power. Power gain of 30dB is obtained with a low quiescent current of 80mA.

The GW5540 power amplifier operate at 802.11g mode (OFDM 64QAM, 54Mbps), it provides a low EVM (Error-Vector magnitude) of 3% at +20dBm linear output power, and consumes 135mA total DC current. The GW5540 low noise amplifier offset 16dB gain, 1.5dB NF and  $P_{1dB} = 2dBm$  at 5.8mA of DC current.

#### **■** Features

- 2.3 2.5GHz Operation
- PA Quiescent Current 80mA
- PA Small Signal Gain 30dB
- PA Total Current 135mA for POUT=20dBm OFDM
- PA EVM ~3 % 54Mbps / 64QAM at POUT=20dBm
- LNA Gain ~ 16 dB
- LNA Noise Figure 1.5dB
- RF Input/Output matched to 50Ω
- Small Footprint: 2.0 × 2.0mm

# ■ APPLICATION

- IEEE 802.11b/g Wireless LAN System
- 2.4GHz ISM Band Application
- 2.4GHz Cordless Phones
- WLAN Pre-n applications

## **■** Electrical Characteristics

**TX** test conditions:  $V_{CC} = 3.3V$ ,  $V_{ref} = 2.73V$ ,  $I_{CO} = 80 \text{mA}$ ,  $T_A = 25 ^{\circ}\text{C}$ 

Parameter Parameter	Test Conditions	Min.	Тур.	Max.	Unit
Frequency Range	- 12-14	2.3	-	2.5	GHz
EVM @ POUT < 20dBm	802.11g OFDM 64 QAM		3.0		%
Output P <sub>1dB</sub>	1dB Gain compression		26		dBm
Total Current @ POUT = 20dBm	802.11g OFDM 64 QAM EVM = 2.5%		135		mA
Pout for 11g Spectral mask	802.11g OFDM 64 QAM		25		dBm
Quiescent Current			80		mA
Bias Control Reference Current	At $I_{CQ} = 80 \text{mA}$		1.15		mA
Small Signal Gain	Pin=-30dBm		30		dB
Power Gain @ POUT = 20dBm			30		dB
Gain Flatness	2.3 – 2.5GHz		±0.2		dB
Input Return Loss	Pin=-30dBm		10		dB
Output Return Loss	Pin=-30dBm		10		dB
Second Harmonic	POUT = 20dBm		-45		dBc
Third Harmonic	POUT = 20dBm		-50		dBc
Total Current @ POUT = 23dBm	802.11b 11Mbps CCK		190		mA
2nd Side Lobe @ 22dBm			-50		dBc
Ramp-On Time			100		ns

Notes: 1. All measurements made in  $50\Omega$  system, unless otherwise specified.

2. All measured data was obtained on a 10mil FR4 evaluation board without heat sink.